Chip Monolithic Ceramic Capacitors (Medium Voltage)



Soft Termination Type GRJ series

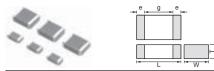
■ Features

- 1. Improves endurance against Board Bending Stress.
- 2. Reduces the board bending stress by the conductive polymer termination.
- 3. Use the GRJ21/31 types with flow or reflow soldering, and other types with reflow soldering

Applications

- 1. Ideal for use on diode-snubber circuits for switching power supplies.
- 2. Ideal for use as primary-secondary coupling for DC-DC converters.
- 3. Ideal for use on line filters and ringer detectors for telephones, facsimiles and modems.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)									
Part Number	L W T		е	g min.						
GRJ21A	2.0 ±0.2	1.25 ±0.2	1.0 +0,-0.3		0.7					
GRJ21B	2.0 ±0.2	1.25 ±0.2	1.25 ±0.2		0.7					
GRJ31B	3.2 +0.2	1.6 +0.2	1.25 +0,-0.3		1.2					
GRJ31C	3.2 ±0.2	1.0 ±0.2	1.6 ±0.2							
GRJ32Q	3.2 ±0.3	2.5 +0.2	1.5 +0,-0.3	0.3 min.	1.2					
GRJ32D		2.5 ±0.2	2.0 +0,-0.3							
GRJ43Q	45104	3.2 ±0.3	1.5 +0,-0.3		22					
GRJ43D	4.5 ±0.4	3.2 ±0.3	2.0 +0,-0.3		2.2					
GRJ55D	5.7 ±0.4	5.0 ±0.4	2.0 +0,-0.3		3.2					

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRJ21AR72E102KWJ1D	DC250	X7R (EIA)	1000pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E152KWJ1D	DC250	X7R (EIA)	1500pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E222KWJ1D	DC250	X7R (EIA)	2200pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E332KWJ1D	DC250	X7R (EIA)	3300pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E472KWJ1D	DC250	X7R (EIA)	4700pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E682KWJ1D	DC250	X7R (EIA)	6800pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21BR72E103KWJ3L	DC250	X7R (EIA)	10000pF ±10%	2.0	1.25	1.25	0.7	0.3 min.
GRJ31BR72E153KWJ1L	DC250	X7R (EIA)	15000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72E223KWJ1L	DC250	X7R (EIA)	22000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31CR72E333KWJ3L	DC250	X7R (EIA)	33000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ31CR72E473KWJ3L	DC250	X7R (EIA)	47000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ31BR72E683KWJ1L	DC250	X7R (EIA)	68000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ32QR72E683KWJ1L	DC250	X7R (EIA)	68000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ31CR72E104KWJ3L	DC250	X7R (EIA)	0.10μF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ32DR72E104KWJ1L	DC250	X7R (EIA)	0.10μF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32QR72E154KWJ1L	DC250	X7R (EIA)	0.15μF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ43QR72E154KWJ1L	DC250	X7R (EIA)	0.15μF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRJ32DR72E224KWJ1L	DC250	X7R (EIA)	0.22μF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43DR72E224KWJ1L	DC250	X7R (EIA)	0.22μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ43DR72E334KWJ1L	DC250	X7R (EIA)	0.33μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72E334KWJ1L	DC250	X7R (EIA)	0.33μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ43DR72E474KWJ1L	DC250	X7R (EIA)	0.47μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72E474KWJ1L	DC250	X7R (EIA)	0.47μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ55DR72E105KWJ1L	DC250	X7R (EIA)	1.0μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ31BR72J102KWJ1L	DC630	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J152KWJ1L	DC630	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J222KWJ1L	DC630	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.

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For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRJ31BR72J332KWJ1L	DC630	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J472KWJ1L	DC630	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J682KWJ1L	DC630	X7R (EIA)	6800pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J103KWJ1L	DC630	X7R (EIA)	10000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31CR72J153KWJ3L	DC630	X7R (EIA)	15000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ32QR72J223KWJ1L	DC630	X7R (EIA)	22000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32DR72J333KWJ1L	DC630	X7R (EIA)	33000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32DR72J473KWJ1L	DC630	X7R (EIA)	47000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43QR72J683KWJ1L	DC630	X7R (EIA)	68000pF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRJ43DR72J104KWJ1L	DC630	X7R (EIA)	0.10μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72J154KWJ1L	DC630	X7R (EIA)	0.15μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ55DR72J224KWJ1L	DC630	X7R (EIA)	0.22μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ31BR73A471KWJ1L	DC1000	X7R (EIA)	470pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A102KWJ1L	DC1000	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A152KWJ1L	DC1000	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A222KWJ1L	DC1000	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A332KWJ1L	DC1000	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A472KWJ1L	DC1000	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ32QR73A682KWJ1L	DC1000	X7R (EIA)	6800pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32QR73A103KWJ1L	DC1000	X7R (EIA)	10000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32DR73A153KWJ1L	DC1000	X7R (EIA)	15000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32DR73A223KWJ1L	DC1000	X7R (EIA)	22000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43DR73A333KWJ1L	DC1000	X7R (EIA)	33000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ43DR73A473KWJ1L	DC1000	X7R (EIA)	47000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR73A104KWJ1L	DC1000	X7R (EIA)	0.10μF ±10%	5.7	5.0	2.0	3.2	0.3 min.

GRJ Series Specifications and Test Methods

No.	Ite	em	Specifications		Test Method		
1	Operating Temperatu	ıre Range	-55 to +125°C		-		
2	Appearar	nce	No defects or abnormalities	Visual inspection			
3	Dimensio	ns	Within the specified dimensions	Using calipers and	micrometers		
4	Dielectric	: Strength	No defects or abnormalities	applied between the	e observed when voltage in the Table is e terminations for 1 to 5 sec., provided the urrent is less than 50mA. Test Voltage 200% of the rated voltage 150% of the rated voltage 120% of the rated voltage		
5	Insulation F	Resistance	C≥0.01μF: More than 100M Ω • μF C<0.01μF: More than 10,000M Ω		tance should be measured with DC500±50V to of rated voltage: DC250V) and within 60±5		
6	Capacita	nce	Within the specified tolerance	Th /D			
7	Dissipation Factor (D		0.025 max.	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V(r.m.s.)			
8	Capacitance 3 Temperature Characteristics		Cap. Change Within ±15% (Temp. Range: -55 to +125°C)	Step 1 2 3 4 5 • Pretreatment Perform a heat tre let sit for 24±2 hrs	Temperature (°C) 25±2 Min. Operating Temp.±3 25±2 Max. Operating Temp.±2 25±2 satment at 150±2°° C for 60±5 min. and then at room condition.*		
9	Adhesive Strength of Termination		No removal of the terminations or other defect should occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. 10N, 10±1s Glass Epoxy Board Fig. 1			
		Appearance	No defects or abnormalities	Solder the capacitor to the test jig (glass epoxy board).			
		Capacitance	Within the specified tolerance		Id be subjected to a simple harmonic motion itude of 1.5mm, the frequency being varied		
10	Vibration Resistance	D.F. 0.025 max.		uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applie for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.). Solder resist Glass Epoxy Board			

^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

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GRJ Series Specifications and Test Methods

Continued from the preceding page.

No.	Iter	m		SI	pecification	S			Test Method		
		Appearance	No marking defects					Solder the capacitor to the testing jig (glass epoxy board) show in Fig. 2.			
11 Deflection		Ţ.	LXW (mm) 2.0×1.25 3.2×1.6 3.2×2.5 4.5×3.2	a 1.2 2.2 2.2 3.5	b 4.0 5.0 5.0 7.0	04.5 1:1.6 ion (mm) C 1.65 2.0 2.9 3.7	d 1.0	Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. 20 50 Pressurizing speed: 1.0mm/s Pressurize Pressurize Capacitance meter 45 (in mm) Fig. 3			
			5.7×5.0	4.5	8.0	5.6		1			
	Solderability of Termination 75% of			75% of the terminations are to be soldered evenly and continuously.					Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder		
		Appearance	No marking defects					Preheat the capacitor at 120 to 150°C* for 1 min.			
		Capacitance Change	Within ±10%					Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s			
	. [D.F.	0.025 max.					Pretreatment			
Resista 13 to Solo Heat		I.R.	C≥0.01μF: More than $100M\Omega$ • μF C<0.01μF: More than $10,000M\Omega$					Perform a heat treatment at 150 [±] -18°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*			
								*Preheating f	or more than 3.2×2.5mm		
		Dielectric Strength	In accordance with item No.4					Step 1 2	Temperature 100 to 120°C 170 to 200°C	Time 1 min. 1 min.	
		Appearance	No marking defe	ects				Fix the capacitor to the supporting jig (glass epoxy board) show			
		Capacitance Change	Within ±7.5%					in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed i			
		D.F.	0.025 max.					the following table. Let sit for 24±2 hrs. at room condition,* then measure.			
			C≧0.01μF: More	e than 100	MO. • IIF			Step	Temperature (°C)	Time (min.)	
		I.R.	C<0.01μF: More					1	Min. Operating Temp.±3	30±3	
	-		· · · · · · · · · · · · · · · · · · ·					2	Room Temp.	2 to 3	
								3 4	Max. Operating Temp.±2 Room Temp.	30±3 2 to 3	
14 Temper Cycle		Dielectric						Pretreatme Perform a he	nt eat treatment at 150 [±] ₁ 8°C fo £2 hrs. at room condition.*		
		Strength	In accordance v	vith item No	No.4						

measure.

Glass Epoxy Board Fig. 4

Perform a heat treatment at 150⁺₁0°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*

Let the capacitor sit at 40±2°C and relative humidity of 90 to 95%

Continued on the following page.





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State)

Appearance

Capacitance

I.R.

Dielectric

Strength

No marking defects

C≧0.01μF: More than 10MΩ • μF

C<0.01 μ F: More than 1,000M Ω

In accordance with item No.4

Within ±15%

for 500±24hrs. Change Humidity Remove and let sit for 24±2 hrs. at room condition,* then D.F. 0.05 max. (Steady

Pretreatment

^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

GRJ Series Specifications and Test Methods

Continued from the preceding page.

No.	Ite	em	Specifications	Test Method				
		Appearance Capacitance	No marking defects Within ±15% (rated voltage: DC250V, DC630V)	Apply voltage as in Table for 1,000 ^{±48} _o hrs. at maximum operating temperature ±3°C. Remove and let sit for 24±2 hrs. at room condition,* then measure.				
		Change D.F.	Vithin ±20% (rated voltage: DC1kV) .05 max.		Rated Voltage Applied Voltage DC250V 150% of the rated voltage			
16	Life	I.R.	C≥0.01μF: More than 10MΩ • μF C<0.01μF: More than 1,000MΩ		DC630V DC1kV	120% of the rated voltage 110% of the rated voltage		
		Dielectric Strength	In accordance with item No.4	The charge/discharge current is less than 50mA. •Pretreatment Apply test voltage for 60±5 min. at test temperature. Remove and let sit for 24±2 hrs. at room condition.*				
		Appearance	No marking defects	Apply the rated voltage at 40±2°C and relative humidity of 90 to 95% for 500±2dhrs.				
	Humidity Loading	Capacitance Change	Within ±15%					
17	(Application: DC250V, DC630V item)	D.F.	0.05 max.		Remove and let sit for 24±2 hrs. at room condition,* then measure.			
		I.R.	C≧0.01μF: More than 10MΩ • μF C<0.01μF: More than 1,000MΩ	Pretreatment Apply test voltage for 60±5 min. at test temperature. Remove and let sit for 24±2 hrs. at room condition.*				
		Dielectric Strength	In accordance with item No.4					

^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

